CEL

Silicon Transistor

NE97833 / 2SA1978

JEITA Part No.

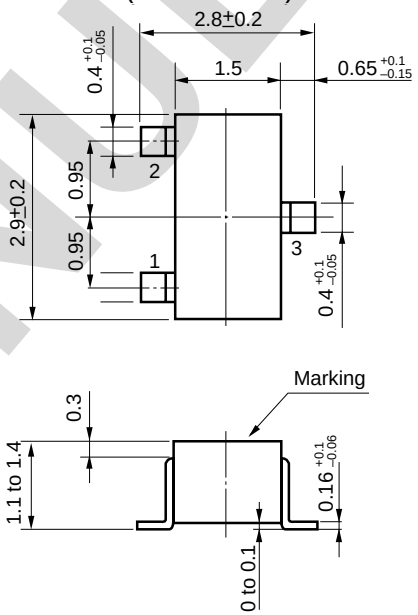
PNP EPITAXIAL SILICON TRANSISTOR MICROWAVE AMPLIFIER

FEATURES

- High f_T
  f_T = 5.5 GHz TYP.
- $|S_{21e}|^2$ = 10.0 dB TYP. @f = 1.0 GHz, V_{CE} = –10 V, I_C = –15 mA
- High speed switching characteristics
- Equivalent NPN transistor is the NE02133 / 2SC2351.
- Alternative of the 2SA1424.

PACKAGE DIMENSIONS

(in milimeters)



PIN CONNECTIONS
1: Emitter
2: Base
3: Collector Marking: T93

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CB0}	–20	V
Collector to Emitter Voltage	V_{CE0}	–12	V
Emitter to Base Voltage	V_{EB0}	–3.0	V
Collector Current	I_C	–50	mA
Total Power Dissipation	P_T	200	mW
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	–65 to +150	°C

ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Collector Cutoff Current	I_{CB0}	V_{CB} = –10 V			–0.1	μA
Emitter Cutoff Current	I_{EB0}	V_{EB} = –2 V			–0.1	μA
DC Current Gain	h_{FE}	V_{CE} = –10 V, I_C = –15 mA	20	40	100	
Gain Bandwidth Product	f_T	V_{CE} = –10 V, I_C = –15 mA	4.0	5.5		GHz
Collector Capacitance	C_{re}*	V_{CB} = –10 V, I_E = 0, f = 1 MHz		0.5	1	pF
Insertion Power Gain	$\|S_{21e}\|^2$	V_{CE} = –10 V, I_C = –15 mA, f = 1.0 GHz	8.0	10.0		dB
Noise Figure	NF	V_{CE} = –10 V, I_C = –3.0 mA, f = 1 GHz		2.0	3	dB

* Mesured by a 3-terminal bridge. Emitter and Case should be connected to the guard terminal.

h_{FE} Classification

Rank	FB
Marking	T93
h_{FE}	20 to 100

ORDERING INFORMATION

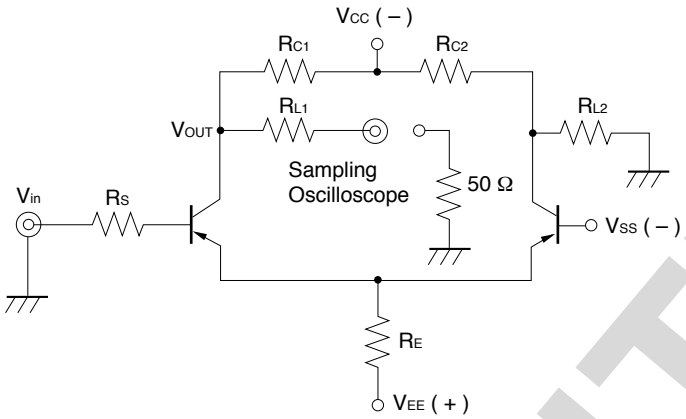
Part Number	Order Number	Quantity
NE97833-T1B 2SA1978-T1B	NE97833-T1B-A 2SA1978-T1B-A	3 kpcs/Reel

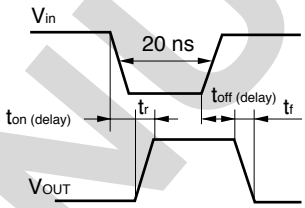
Document No. P11028EJ1V0DS00 (1st edition)
Date Published April 1996 P

SWITCHING CHARACTERISTICS

Parameter	Symbol	V_{in} = 1 V	Unit
		TYP	
Turn-on Delay Time	t_{on} (delay)	1.10	ns
Rise Time	t_r	0.77	ns
Turn off Delay Time	t_{off} (delay)	0.40	ns
Fall Time	t_f	0.79	ns

SWITCHING TIME MEASUREMENT CIRCUIT

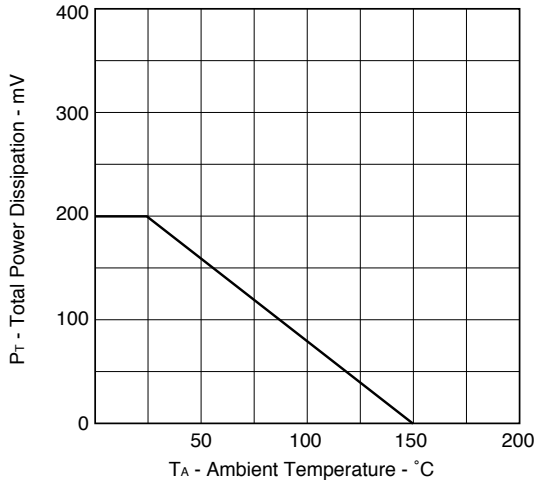




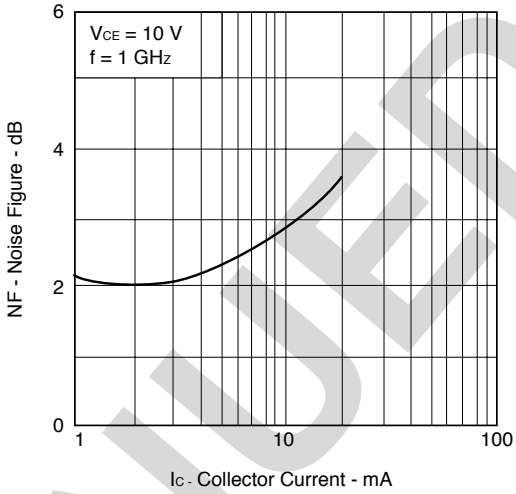
V_{in} = 1 V, V_{BB} = –0.5 V, R_{C1} = R_{C2}						
R_S (Ω)	R_C (Ω)	R_{L1} (Ω)	R_{L2} (Ω)	R_E (Ω)	V_{EE} (V)	V_{CC} (V)
160	1 k	200	250	2.7 k	27	26.3

TYPICAL CHARACTERISTICS

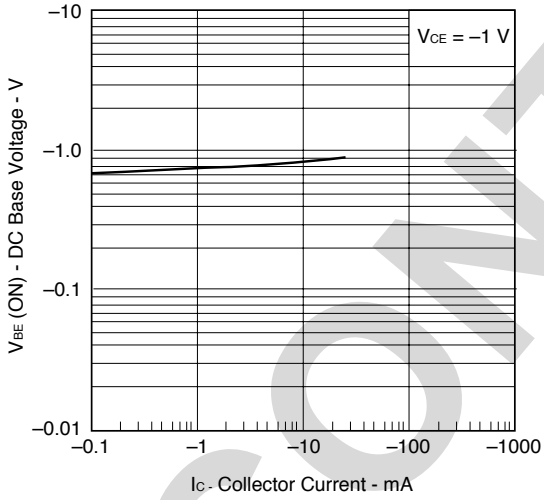
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



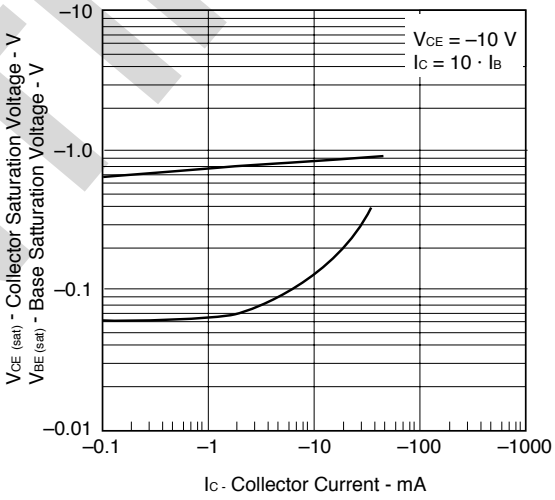
NOISE FIGURE vs. COLLECTOR CURRENT



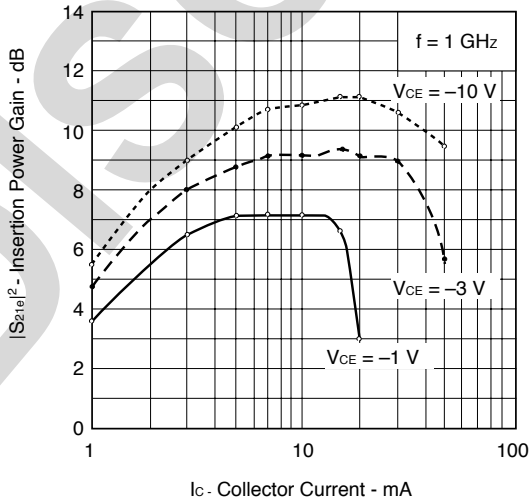
BASE TO EMITTER VOLTAGE vs. COLLECTOR CURRENT



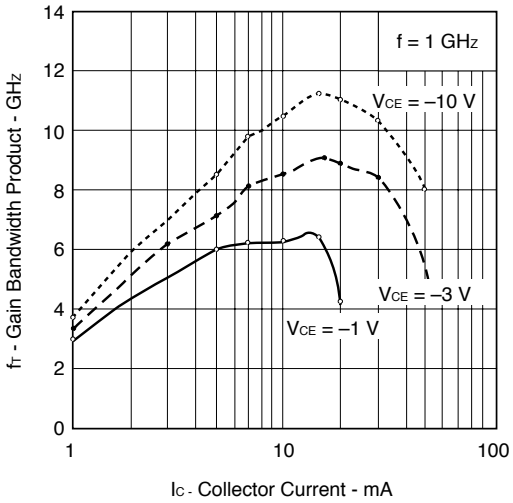
COLLECTOR SATURATION AND BASE TO EMITTER VOLTAGE vs. COLLECTOR CURRENT



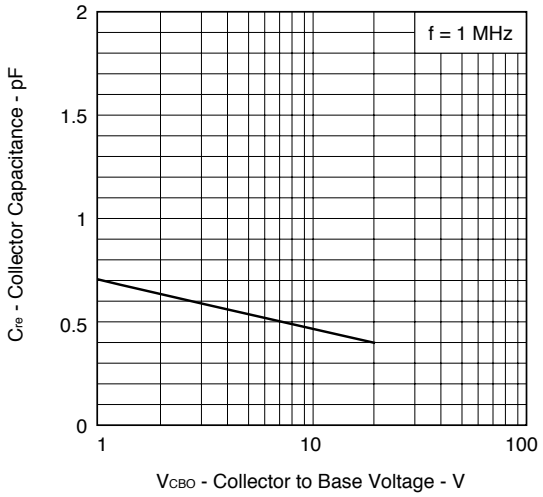
INSERTION GAIN vs. COLLECTOR CURRENT



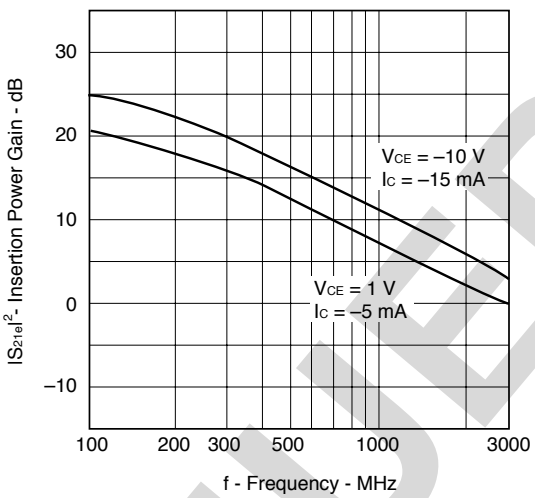
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



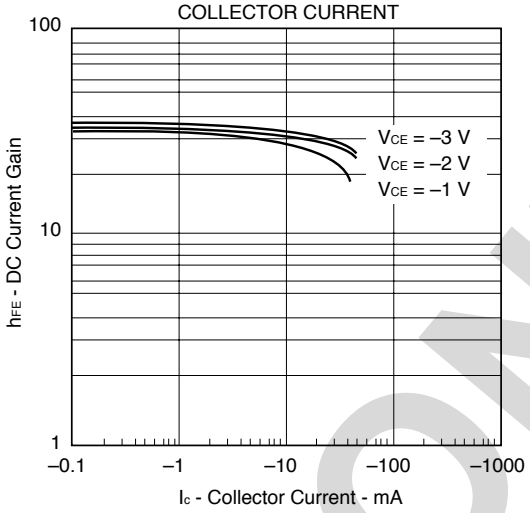
FEED-BACK CAPACITANCE vs.
COLLECTOR TO BASE VOLTAGE



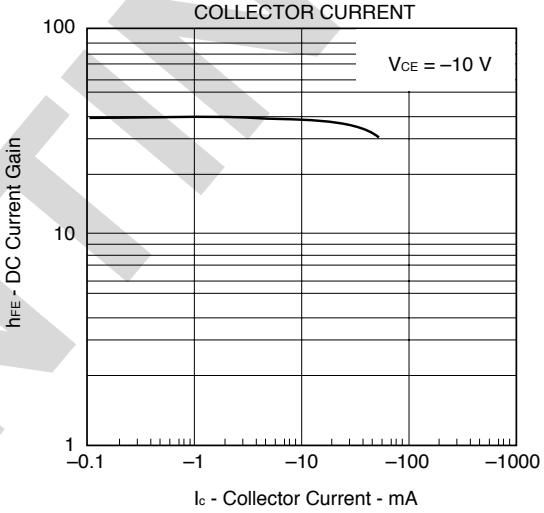
INSERTION GAIN vs. FREQUENCY



DC CURRENT GAIN vs.
COLLECTOR CURRENT

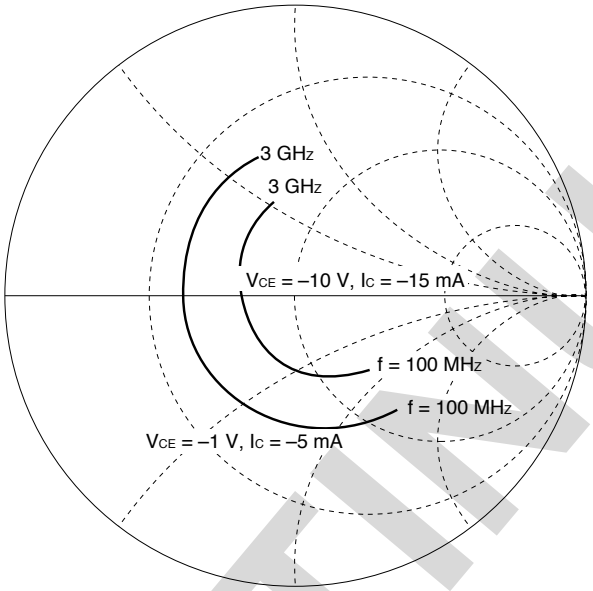


DC CURRENT GAIN vs.
COLLECTOR CURRENT

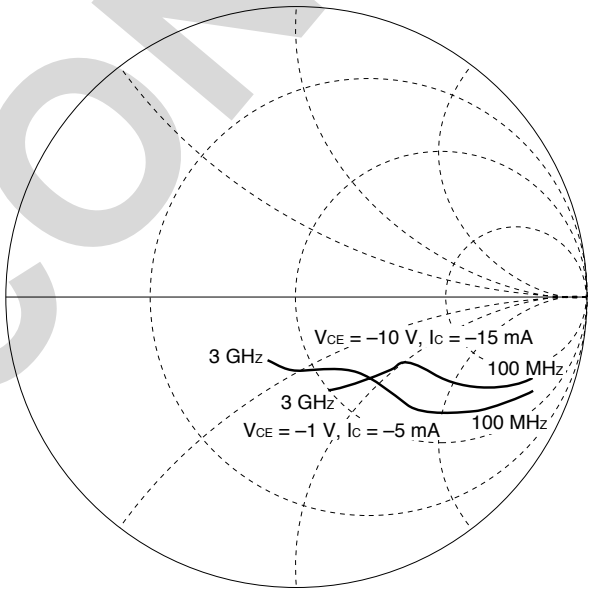


S-PARAMETER

S11



S22



S-PARAMETER

(V_{CE} = 1 V, I_C = 5 mA, Zo = 50 Ω)

f	S_{11}		S_{21}		S_{12}		S_{22}	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100	0.527	– 47.1	10.5	149.	0.0359	70.6	0.881	– 21.1
200	0.468	– 83.4	8.37	128.	0.0584	58.7	0.716	– 34.2
300	0.427	– 109	6.63	114.	0.0729	53.6	0.586	– 40.9
400	0.407	– 128	5.36	104.	0.0835	52.1	0.503	– 44.3
500	0.393	– 143	4.46	96.6	0.0930	52.1	0.443	– 45.8
600	0.388	– 154	3.82	90.2	0.100	53.1	0.401	– 46.7
700	0.386	– 164	3.34	84.9	0.109	53.3	0.373	– 47.7
800	0.388	– 172	2.96	80.1	0.118	54.4	0.351	– 49.1
900	0.392	– 179	2.67	75.8	0.128	55.6	0.332	– 50.1
1000	0.394	174	2.43	71.6	0.137	56.4	0.319	– 51.4
1100	0.399	169	2.24	68.1	0.147	56.9	0.306	– 53.2
1200	0.405	163	2.07	64.6	0.158	57.2	0.298	– 54.5
1300	0.410	159	1.93	61.3	0.168	57.6	0.289	– 57.0
1400	0.416	154	1.81	58.0	0.179	57.7	0.280	– 59.3
1500	0.422	150	1.71	54.9	0.190	57.7	0.274	– 61.2
1600	0.431	147	1.62	52.0	0.201	57.7	0.267	– 64.4
1700	0.438	143	1.54	49.3	0.213	57.5	0.262	– 66.7
1800	0.445	140	1.47	46.6	0.224	57.2	0.259	– 70.3
1900	0.451	136	1.41	44.1	0.236	56.8	0.252	– 73.6
2000	0.460	133	1.35	41.5	0.248	56.3	0.247	– 76.3
2100	0.465	130	1.30	39.2	0.261	55.7	0.243	– 80.2
2200	0.473	127	1.26	36.9	0.273	55.1	0.239	– 84.4
2300	0.481	125	1.21	34.8	0.286	54.3	0.234	– 87.2
2400	0.487	122	1.17	32.5	0.299	53.3	0.235	– 91.9
2500	0.493	119	1.14	30.6	0.312	52.6	0.230	– 95.9

S-PARAMETER

(V_{CE} = 3 V, I_C = 5 mA, Zo = 50 Ω)

f	S_{11}		S_{21}		S_{12}		S_{22}	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100	0.558	– 37.1	11.0	153.	0.0288	74.3	915	– 16.3
200	0.485	– 67.9	9.13	133.	0.0467	83.0	784	– 27.0
300	0.423	– 92.5	7.48	119.	0.0611	58.1	670	– 33.0
400	0.381	– 111	6.21	109.	0.0703	56.5	590	– 36.0
500	0.353	– 127	5.18	101.	0.0801	56.1	531	– 37.4
600	0.339	– 140	4.47	95.1	0.0880	56.7	490	– 38.1
700	0.329	– 151	3.92	89.9	0.0938	57.5	461	– 33.8
800	0.325	– 160	3.48	84.9	0.104	57.9	438	– 39.8
900	0.325	– 169	3.14	80.7	0.113	58.7	419	– 40.4
1000	0.326	– 176	2.87	76.9	0.122	59.5	408	– 41.6
1100	0.330	177	2.64	73.0	0.131	60.5	393	– 42.8
1200	0.335	170	2.44	69.6	0.140	61.2	386	– 44.0
1300	0.339	165	2.28	66.5	0.150	61.3	377	– 45.9
1400	0.345	160	2.13	63.3	0.160	61.9	366	– 47.5
1500	0.351	155	2.01	60.2	0.170	61.9	362	– 49.0
1600	0.360	151	1.90	57.4	0.181	61.8	354	– 51.0
1700	0.366	147	1.81	54.6	0.191	61.8	349	– 53.0
1800	0.374	143	1.72	52.0	0.202	61.7	344	– 55.5
1900	0.382	140	1.65	49.5	0.213	61.3	337	– 58.1
2000	0.390	137	1.58	47.0	0.223	61.0	334	– 60.4
2100	0.396	133	1.52	44.6	0.233	60.4	328	– 63.0
2200	0.404	130	1.46	42.4	0.243	60.2	321	– 65.9
2300	0.413	127	1.41	40.2	0.251	59.4	318	– 68.3
2400	0.418	125	1.36	38.0	0.273	58.9	314	– 72.1
2500	0.427	122	1.32	35.9	0.255	58.2	303	– 74.8

S-PARAMETER

(V_{CE} = 10 V, I_C = 5 mA, Zo = 50 Ω)

f	S_{11}		S_{21}		S_{12}		S_{22}	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100	0.529	– 28.8	11.3	156.	0.0234	75.4	0.939	– 12.8
200	0.548	– 53.5	9.70	138.	0.0412	67.4	0.836	– 21.7
300	0.463	– 73.9	8.20	124.	0.0530	62.1	0.739	– 27.2
400	0.400	– 91.4	6.94	114.	0.0620	59.7	0.666	– 29.9
500	0.349	– 106	5.86	106.	0.0712	58.9	0.608	– 31.4
600	0.316	– 119	5.09	100.	0.0793	59.8	0.567	– 31.9
700	0.292	– 131	4.49	94.6	0.0860	59.6	0.539	– 32.7
800	0.277	– 141	4.00	89.7	0.0938	60.4	0.516	– 33.5
900	0.267	– 152	3.63	85.4	0.101	61.3	0.498	– 34.2
1000	0.261	– 160	3.31	81.5	0.109	61.9	0.485	– 35.1
1100	0.259	– 169	3.04	77.9	0.117	62.8	0.472	– 35.9
1200	0.260	– 177	2.82	74.5	0.125	63.2	0.463	– 36.9
1300	0.263	176	2.63	71.3	0.133	63.9	0.455	– 38.4
1400	0.267	169	2.46	68.2	0.143	64.4	0.448	– 39.5
1500	0.272	164	2.32	65.3	0.152	64.5	0.440	– 40.8
1600	0.280	159	2.20	62.5	0.161	64.6	0.434	– 42.5
1700	0.286	154	2.09	59.8	0.171	64.9	0.428	– 44.1
1800	0.293	149	1.99	57.3	0.191	64.8	0.423	– 46.0
1900	0.300	145	1.90	54.8	0.192	64.4	0.417	– 47.8
2000	0.308	141	1.82	52.3	0.201	64.5	0.413	– 49.7
2100	0.315	138	1.75	49.9	0.212	63.9	0.408	– 51.9
2200	0.325	134	1.68	47.6	0.223	63.8	0.402	– 54.3
2300	0.333	131	1.63	45.5	0.235	63.2	0.397	– 56.1
2400	0.341	128	1.57	43.3	0.246	62.7	0.395	– 58.7
2500	0.348	125	1.52	41.2	0.258	62.1	0.388	– 61.0

S-PARAMETER

(V_{CE} = 10 V, I_C = 15 mA, Zo = 50 Ω)

f	S_{11}		S_{21}		S_{12}		S_{22}	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100	0.354	– 46.6	17.87	147.	0.0190	74.6	866	– 18.3
200	0.290	– 81.8	13.45	125.	0.0317	70.0	708	– 26.9
300	0.247	– 107	10.35	113.	0.0420	68.4	601	– 29.8
400	0.226	– 126	8.294	104.	0.0518	68.3	539	– 30.5
500	0.215	– 141	6.799	97.8	0.0626	69.8	497	– 30.2
600	0.210	– 154	5.805	92.4	0.0720	70.8	470	– 30.1
700	0.208	– 164	5.050	88.1	0.0820	71.0	450	– 30.2
800	0.211	– 172	4.475	84.1	0.0919	70.9	435	– 30.6
900	0.215	179	4.008	80.5	0.102	70.9	423	– 31.1
1000	0.218	172	3.647	77.2	0.112	70.7	415	– 32.2
1100	0.225	166	3.345	74.2	0.121	70.9	405	– 32.9
1200	0.232	160	3.086	71.1	0.133	70.3	400	– 34.2
1300	0.237	156	2.871	68.4	0.143	70.2	394	– 35.7
1400	0.244	151	2.685	65.7	0.153	69.7	386	– 36.8
1500	0.251	147	2.532	63.2	0.165	69.2	381	– 38.4
1600	0.261	143	2.392	60.5	0.174	68.7	376	– 39.9
1700	0.268	140	2.265	58.2	0.185	68.0	373	– 41.6
1800	0.276	137	2.155	55.7	0.196	67.3	366	– 43.7
1900	0.284	134	2.059	53.5	0.207	66.5	360	– 45.7
2000	0.292	131	1.974	51.1	0.219	65.8	356	– 47.5
2100	0.299	128	1.897	49.0	0.230	65.1	350	– 49.7
2200	0.308	125	1.826	46.9	0.242	64.2	345	– 51.8
2300	0.317	123	1.763	44.7	0.252	63.3	341	– 53.8
2400	0.324	121	1.697	42.7	0.264	62.4	337	– 56.7
2500	0.332	119	1.646	40.7	0.276	61.5	331	– 58.8

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